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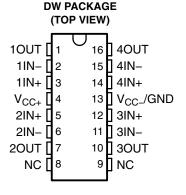
- Single-Supply Operation: Input Voltage Range Extends to Ground, and Output Swings to Ground While Sinking Current
- Input Offset Voltage 300 μV Max at 25°C for LT1014
- Offset Voltage Temperature Coefficient 2.5 μV/°C Max for LT1014
- Input Offset Current 1.5 nA Max at 25°C for LT1014
- High Gain 1.2 V/ $\mu$ V Min (R<sub>L</sub> = 2 kΩ), 0.5 V/ $\mu$ V Min (R<sub>L</sub> = 600 Ω) for LT1014
- Low Supply Current 2.2 mA Max at 25°C for LT 1014
- Low Peak-to-Peak Noise Voltage 0.55 μV Typ
- Low Current Noise 0.07 pA/√Hz Typ

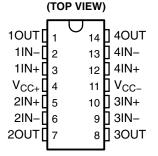
#### description

The LT1014, LT1014A, and LT1014D are quad precision operational amplifiers with 14-pin industry-standard configuration. They feature low offset-voltage temperature coefficient, high gain, low supply current, and low noise.

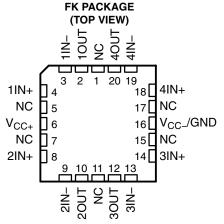
The LT1014, LT1014A, and LT1014D can be operated with both dual  $\pm 15$ -V and single 5-V power supplies. The common-mode input voltage range includes ground, and the output voltage can also swing to within a few milivolts of ground. Crossover distortion is eliminated.

The LT1014C and LT1014D are characterized for operation from 0°C to 70°C. The LT1014I and LT1014DI are characterized for operation from –40°C to 105°C. The LT1014M, LT1014AM and LT1014DM are characterized for operation over the full military temperature range of –55°C to 125°C.





J OR N PACKAGE



NC - No internal connection



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



# LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

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#### **AVAILABLE OPTIONS**<sup>†</sup>

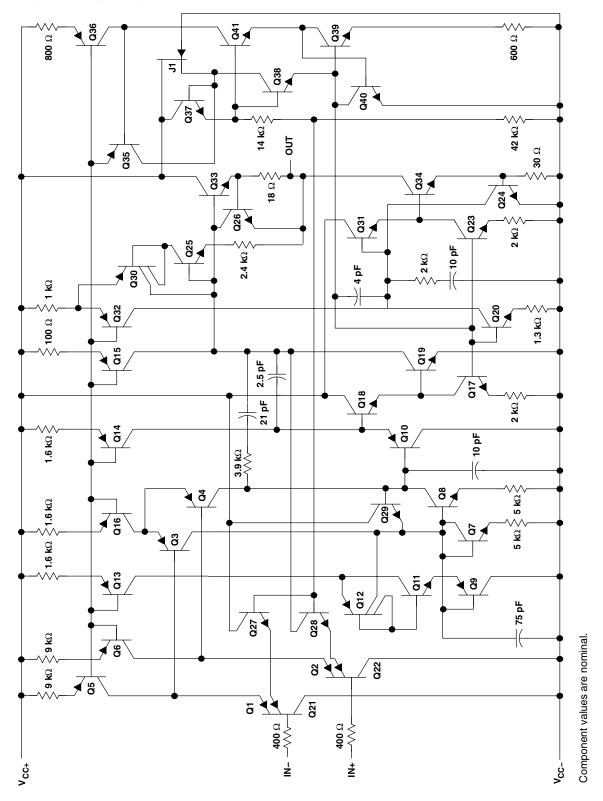
			PACKAGED	DEVICES <sup>‡</sup>	
T <sub>A</sub>	V <sub>IO</sub> max AT 25°C	SMALL OUTLINE (DW) <sup>§</sup>	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)
0°C to 70°C	300 μV 800 μV	— LT1014DDW		1 1	LT1014CN LT1014DN
-40°C to 105°C	300 μV 800 μV	— LT1014DIDW		1 1	LT1014IN LT1014DIN
-55°C to 125°C	180 μV — 5°C 300 μV — 800 μV LT1014DMDW		LT1014AMFK LT1014MFK —	LT1014AMJ LT1014MJ —	— LT1014MN LT1014DMN

<sup>&</sup>lt;sup>†</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

<sup>&</sup>lt;sup>‡</sup> Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

<sup>§</sup> The DW package is available taped and reeled. Add the suffix R to the device type (e.g., LT1014DDWR).

### schematic (each amplifier)



### LT1014, LT1014A, LT1014D **QUAD PRECISION OPERATIONAL AMPLIFIERS**

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#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage (see Note 1): V <sub>CC+</sub>	
V <sub>CC-</sub>	
Differential input voltage (see Note 2)	±30 V
Input voltage range, V <sub>I</sub> (any input) (see Note 1)	$V_{CC-}$ – 5 V to $V_{CC+}$
Duration of short-circuit current at (or below) T <sub>A</sub> = 25°C (see Note 3)	Unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub> : LT1014C, LT1014D	–0°C to 70°C
LT1014I, LT1014DI	–40°C to 105°C
LT1014M, LT1014AM, LT1014DM .	–55°C to 125°C
Case temperature for 60 seconds: FK package	260°C
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V<sub>CC+</sub> and V<sub>CC-</sub>
  - 2. Differential voltages are at the noninverting input with respect to the inverting input.
  - 3. The output may be shorted to either supply.

#### **DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 105°C POWER RATING	T <sub>A</sub> = 125°C POWER RATING
DW	1025 mV	8.2 mW/°C	656 mW	369 mW	205 mW
FK	1375 mV	11.0 mW/°C	880 mW	495 mW	275 mW
J	1375 mV	11.0 mW/°C	880 mW	495 mW	275 mW
N	1150 mV	9.2 mW/°C	736 mW	414 mW	230 mW

# LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

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# electrical characteristics at specified free-air temperature, $V_{CC\pm}=\pm 15$ V, $V_{IC}=0$ (unless otherwise noted)

	DADAMETED	TECT COMPITIONS		ı	_T1014C		I	T1014D		
	PARAMETER	TEST CONDITIONS	T <sub>A</sub> †	MIN	TYP <sup>‡</sup>	MAX	MIN	TYP <sup>‡</sup>	MAX	UNIT
V	Innut effect veltage	D 50.0	25°C		60	300		200	800	/
V <sub>IO</sub>	Input offset voltage	$R_S = 50 \Omega$	Full range			550			1000	μV
$\alpha_{V_{IO}}$	Temperature coeficient of input offset voltage		Full range		0.4	2.5		0.7	5	μV/°C
	Long-term drift of input offset voltage		25°C		0.5			0.5		μV/mo
	loon at affect accomment		25°C		0.15	1.5		0.15	1.5	^
I <sub>IO</sub>	Input offset current		Full range			2.8			2.8	nA
	land biogramment		25°C		-12	-30		-12	-30	^
I <sub>IB</sub>	Input bias current		Full range			-38			-38	nA
V <sub>ICR</sub>	Common-mode		25°C	-15 to 13.5	-15.3 to 13.8		–15 to 13.5	-15.3 to 13.8		٧
ЮП	input voltage range		Full range	-15 to 13			-15 to 13			
V	Maximum peak output	$R_L = 2 k\Omega$	25°C	±12.5	±14		±12.5	±14		٧
V <sub>OM</sub>	voltage swing	HL = 2 K22	Full range	±12			±12			V
	Laura alaura laliffa ann ilal	$V_0 = \pm 10 \text{ V}, \qquad R_L = 600 \Omega$	25°C	0.5	2		0.5	2		
$A_{VD}$	Large-signal differential voltage amplification	$V_{O} = \pm 10 \text{ V},  R_{L} = 2 \text{ k}\Omega$	25°C	1.2	8		1.2	8		V/µV
	renage ampimoation	$V_0 = \pm 10 \text{ V},  R_1 = 2 \text{ K}22$	Full range	0.7			0.7			
CMRR	Common-mode	$V_{IC} = -15 \text{ V to } 13.5 \text{ V}$	25°C	97	117		97	117		dB
CIVINN	rejection ratio	$V_{IC} = -15 \text{ V to } 13 \text{ V}$	Full range	94			94			uБ
	Supply-voltage		25°C	100	117		100	117		
k <sub>SVR</sub>	rejection ratio $(\Delta V_{CC}/\Delta V_{IO})$	$V_{CC\pm} = \pm 2 \text{ V to } \pm 18 \text{ V}$	Full range	97			97			dB
	Channel separation	$V_O = \pm 10 \text{ V}, \qquad R_L = 2 \text{ k}\Omega$	25°C	120	137		120	137		dB
r <sub>id</sub>	Differential input resistance		25°C	70	300		70	300		МΩ
r <sub>ic</sub>	Common-mode input resistance		25°C		4			4		GΩ
loo	Supply current		25°C		0.35	0.55		0.35	0.55	mA
I <sub>CC</sub>	per amplifier		Full range			0.6			0.6	ША

<sup>†</sup> Full range is 0°C to 70°C.

<sup>&</sup>lt;sup>‡</sup> All typical values are at  $T_A = 25$ °C.

# LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

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# electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = 5 V, $V_{CC-}$ = 0, $V_{O}$ = 1.4 V, $V_{IC}$ = 0 (unless otherwise noted)

	DADAMETED	TECT COMPLETIONS	- +	I	_T1014C		ı	T1014D		
	PARAMETER	TEST CONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
.,	land offer to the sec	B 500	25°C		90	450		250	950	.,
$V_{IO}$	Input offset voltage	$R_S = 50 \Omega$	Full range			570			1200	μV
	lowed affect accommond		25°C		0.2	2		0.2	2	A
I <sub>IO</sub>	Input offset current		Full range			6			6	nA
	lament biog accompant		25°C		-15	-50		-15	-50	A
I <sub>IB</sub>	Input bias current		Full range			-90			-90	nA
	0		25°C	0	-0.3		0	-0.3		
V <sub>ICR</sub>	Common-mode input voltage range		25 0	to 3.5	to 3.8		to 3.5	to 3.8		٧
	input voitage range		Full range	0 to 3			0 to 3			
		Output low, No load	25°C		15	25		15	25	
		Output low,	25°C		5	10		5	10	mV
		$R_L = 600 \Omega$ to GND	Full range			13			13	mv
$V_{OM}$	Maximum peak output voltage swing	Output low, $I_{sink} = 1 \text{ mA}$	25°C		220	350		220	350	
	voltage swing	Output high, No load	25°C	4	4.4		4	4.4		
		Output high,	25°C	3.4	4		3.4	4		٧
		$R_L = 600 \Omega$ to GND	Full range	3.2			3.2			
A <sub>VD</sub>	Large-signal differential voltage amplification	$V_O$ = 5 mV to 4 V, $R_L$ = 500 $\Omega$	25°C		1			1		V/μV
1	Supply current		25°C		0.3	0.5		0.3	0.5	mA
I <sub>CC</sub>	per amplifier		Full range			0.55			0.55	IIIA

<sup>&</sup>lt;sup>†</sup> Full range is 0°C to 70°C.

# operating characteristics, $V_{CC}\pm$ = $\pm15$ V, $V_{IC}$ = 0, $T_{A}$ = $25^{\circ}C$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate		0.2	0.4		V/µs
.,	Facility described to the control of	f = 10 Hz		24		->4/1
V <sub>n</sub>	Equivalent input noise voltage	f = 1 kHz		22		nV/√ <del>Hz</del>
V <sub>N(PP)</sub>	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 10 Hz		0.55		μV
In	Equivalent input noise current	f = 10 Hz		0.07		pA/√ <del>Hz</del>

# LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

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# electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = $\pm 15$ V, $V_{IC}$ = 0 (unless otherwise noted)

		TEGT COMPLETIONS			LT1014I		L	T1014D		
	PARAMETER	TEST CONDITIONS	T <sub>A</sub> †	MIN	TYP <sup>‡</sup>	MAX	MIN	TYP <sup>‡</sup>	MAX	UNIT
,,	land official values	D 500	25°C		60	300		200	800	
V <sub>IO</sub>	Input offset voltage	$R_S = 50 \Omega$	Full range			550			1000	μV
$\alpha_{V_{IO}}$	Temperature coeficient of input offset voltage		Full range		0.4	2.5		0.7	5	μV/°C
	Long-term drift of input offset voltage		25°C		0.5			0.5		μV/mo
1	Input offset current		25°C		0.15	1.5		0.15	1.5	nA
I <sub>IO</sub>	input offset current		Full range			2.8			2.8	ΠA
	Input bias current		25°C		-12	-30		-12	-30	nA
I <sub>IB</sub>	input bias current		Full range			-38			-38	IIA
V <sub>ICR</sub>	Common-mode input voltage range		25°C	-15 to 13.5	-15.3 to 13.8		-15 to 13.5	-15.3 to 13.8		V
	input voitage range		Full range	–15 to 13			-15 to 13			
V	Maximum peak	$R_L = 2 k\Omega$	25°C	±12.5	±14		±12.5	±14		V
V <sub>OM</sub>	output voltage swing	HL = 2 KS2	Full range	±12			±12			V
	Lorge signal differential	$V_0 = \pm 10 \text{ V}, \qquad R_L = 600 \Omega$	25°C	0.5	2		0.5	2		
$A_{VD}$	Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V},  R_L = 2 \text{ k}\Omega$	25°C	1.2	8		1.2	8		V/µV
		V() = ±10 V, HL = 2 KS2	Full range	0.7			0.7			
CMRR	Common-mode	$V_{IC} = -15 \text{ V to } 13.5 \text{ V}$	25°C	97	117		97	117		dB
Civil II I	rejection ratio	VIC = -13 V to 13.5 V	Full range	94			94			uБ
	Supply-voltage		25°C	100	117		100	117		
k <sub>SVR</sub>	rejection ratio $(\Delta V_{CC}/\Delta V_{IO})$	$V_{CC\pm} = \pm 2 \text{ V to } \pm 18 \text{ V}$	Full range	97			97			dB
	Channel separation	$V_O = \pm 10 \text{ V}, \qquad R_L = 2 \text{ k}\Omega$	25°C	120	137		120	137		dB
r <sub>id</sub>	Differential input resistance		25°C	70	300		70	300		МΩ
r <sub>ic</sub>	Common-mode input resistance		25°C		4			4		GΩ
Icc	Supply current		25°C		0.35	0.55		0.35	0.55	mA
·CC	per amplifier		Full range			0.6			0.6	шА

<sup>†</sup> Full range is –40°C to 105°C.

<sup>&</sup>lt;sup>‡</sup> All typical values are at  $T_A = 25$ °C.

# LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

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# electrical characteristics at specified free-air temperature, $V_{CC+}$ = 5 V, $V_{CC-}$ = 0, $V_O$ = 1.4 V, $V_{IC}$ = 0 (unless otherwise noted)

	PARAMETER	TEST CONDITIONS			LT1014I		L	.T1014DI		
	PARAMETER	TEST CONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
.,	Laurent affa at continue	B 500	25°C		90	450		250	950	
V <sub>IO</sub>	Input offset voltage	$R_S = 50 \Omega$	Full range			570			1200	μV
	Innut offeet ourrent		25°C		0.2	2		0.2	2	nA
I <sub>IO</sub>	Input offset current		Full range			6			6	ΠA
	Innut bigg gurrant		25°C		-15	-50		-15	-50	nA
I <sub>IB</sub>	Input bias current		Full range			-90			-90	ΠA
	Common-mode		25°C	0 to 3.5	-0.3 to 3.8		0 to 3.5	-0.3 to 3.8		
V/. ~ -	input voltage range		F. II		10 3.8			10 3.8		V
			Full range	0 to 3			0 to 3			
		Output low, No load	25°C		15	25		15	25	
		Output low,	25°C		5	10		5	10	mV
		$R_L = 600 \Omega$ to GND	Full range			13			13	111 V
$V_{OM}$	Maximum peak output voltage swing	Output low, I <sub>sink</sub> = 1 mA	25°C		220	350		220	350	
	output voltage swing	Output high, No load	25°C	4	4.4		4	4.4		
		Output high,	25°C	3.4	4		3.4	4		V
		$R_L = 600 \Omega$ to GND	Full range	3.2			3.2			
A <sub>VD</sub>	Large-signal differential voltage amplification	$V_O = 5$ mV to 4 V, $R_L = 500 \Omega$	25°C		1			1		V/µV
	Supply current		25°C		0.3	0.5		0.3	0.5	mA
Icc	per amplifier		Full range			0.55			0.55	IIIA

<sup>†</sup> Full range is –40°C to 105°C.

# operating characteristics, $V_{CC^+}$ = $\pm 15$ V, $V_{IC}$ = 0, $T_A$ = $25^{\circ}C$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate		0.2	0.4		V/μs
V	Continuous insulancias valtana	f = 10 Hz		24		
V <sub>n</sub>	Equivalent input noise voltage	f = 1 kHz		22		nV/√ <del>Hz</del>
V <sub>N(PP)</sub>	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 10 Hz		0.55		μV
In	Equivalent input noise current	f = 10 Hz		0.07		pA/√ <del>Hz</del>

# LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

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#### electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = $\pm 15$ V, $V_{IC}$ = 0 (unless otherwise noted)

		TEST		L	T1014M		L	Γ1014 <b>Α</b> Ν	Л	Lī	Γ1014DN	Л	
PA	RAMETER	CONDITIONS	T <sub>A</sub> †	MIN	TYP‡	MAX	MIN	TYP‡	MAX	MIN	TYP‡	MAX	UNIT
V <sub>IO</sub>	Input offset	B 50 O	25°C		60	300		60	180		200	800	μV
VIO	voltage	$R_S = 50 \Omega$	Full range			550			350			1000	μν
$\alpha_{V_{IO}}$	Temperature coefficient of input offset voltage		Full range		0.5	2.5		0.5	2		0.5	2.5	μV/°C
	Long-term drift of input offset voltage		25°C		0.5			0.5			0.5		μV/mo
1	Input offset		25°C		0.15	1.5		0.15	8.0		0.15	1.5	nA
I <sub>IO</sub>	current		Full range			5			2.8			5	IIA
l	Input bias		25°C		-12	-30		-12	-20		-12	-30	nA
I <sub>IB</sub>	current		Full range			-45			-30			-45	IIA
V <sub>ICR</sub>	Common-mode input voltage		25°C	-15 to 13.5	-15.3 to 13.8		-15 to 13.5	-15.3 to 13.8		-15 to 13.5	-15.3 to 13.8		V
	range		Full range	-14.9 to 13			-14.9 to 13			-14.9 to 13			
	Maximum peak		25°C	±12.5	±14		±13	±14		±12.5	±14		
V <sub>OM</sub>	output voltage swing	$R_L = 2 k\Omega$	Full range	±11.5			±12			±11.5			٧
	Large-signal differential	$V_O = \pm 10 \text{ V},$ $R_L = 600 \Omega$	25°C	0.5	2		0.8	2.2		0.5	2		\//\/
A <sub>VD</sub>	voltage	$V_{O} = \pm 10 \text{ V},$	25°C	1.2	8		1.5	8		1.2	8		V/µV
	amplification	$R_L = 2 k\Omega$	Full range	0.25			0.4			0.25			
CMRR	Common-mode	$V_{IC} = -15 \text{ V to}$ 13.5 V	25°C	97	117		100	117		97	117		dD
CIVIRR	rejection ratio	$V_{IC} = -14.9 \text{ V}$ to 13 V	Full range	94			96			94			dB
	Supply-voltage	$V_{CC\pm} = \pm 2 \text{ V to}$	25°C	100	117		103	117		100	117		
k <sub>SVR</sub>	rejection ratio $(\Delta V_{CC}/\Delta V_{IO})$	±18 V	Full range	97			100			97			dB
	Channel separation	$V_O = \pm 10 \text{ V},$ $R_L = 2 \text{ k}\Omega$	25°C	120	137		123	137		120	137		dB
r <sub>id</sub>	Differential input resistance		25°C	70	300		100	300		70	300		ΜΩ
r <sub>ic</sub>	Common-mode input resistance		25°C		4			4			4		GΩ
las	Supply current		25°C		0.35	0.55		0.35	0.50		0.35	0.55	m A
Icc	per amplifier		Full range			0.7			0.6			0.7	mA



<sup>†</sup> Full range is –55°C to 125°C. ‡ All typical values are at T<sub>A</sub> = 25°C.

# LT1014, LT1014A, LT1014D QUAD PRECISION OPERATIONAL AMPLIFIERS

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# electrical characteristics at specified free-air temperature, $V_{CC+}$ = 5 V, $V_{CC-}$ = 0, $V_O$ = 1.4 V, $V_{IC}$ = 0 (unless otherwise noted)

	DAMETED	TEST	- +	L	.T1014M		Lī	1014AN	Л	Lī	Γ1014DN	Л	UNIT
PA	ARAMETER	CONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNII
		$R_S = 50\Omega$	25°C		90	450		90	280		250	950	
V <sub>IO</sub>	Input	ns = 5022	Full range		400	1500		400	960		800	2000	μV
10	offset voltage	$R_S = 50\Omega,$ $V_{IC} = 0.1 \text{ V}$	125°C		200	750		200	480		560	1200	μ.
1	Input		25°C		0.2	2		0.2	1.3		0.2	2	
I <sub>IO</sub>	offset current		Full range			10			7			10	nA
١,	Input		25°C		-15	-50		-15	-35		-15	-50	IIA
I <sub>IB</sub>	bias current		Full range			-120			-90			-120	
	Common- mode input		25°C	0 to 3.5	-0.3 to 3.8		0 to 3.5	-0.3 to 3.8		0 to 3.5	-0.3 to 3.8		V
V <sub>ICR</sub>	voltage range		Full range	0.1 to 3			0.1 to 3			0.1 to 3			V
		Output low, No load	25°C		15	25		15	25		15	25	
		Output low,	25°C		5	10		5	10		5	10	
		$R_L = 600\Omega$ to GND	Full range			18			15			18	mV
V <sub>OM</sub>	Maximum peak output voltage swing	Output low, I <sub>sink</sub> = 1 mA	25°C		220	350		220	350		220	350	
	voltage swing	Output high, No load	25°C	4	4.4		4	4.4		4	4.4		
		Output high,	25°C	3.4	4		3.4	4		3.4	4		V
		$R_L = 600\Omega$ to GND	Full range	3.1			3.2			3.1			
A <sub>VD</sub>	Large-signal differential voltage amplification	$V_O = 5$ mV to 4 V, $R_L = 500\Omega$	25°C		1			1			1		V/μV
I <sub>CC</sub>	Supply current		25°C		0.3	0.5		0.3	0.45		0.3	0.5	mA
† F. II	per amplifier		Full range			0.65			0.55			0.65	11171

<sup>†</sup> Full range is –55°C to 125°C.

# operating characteristics, $V_{CC\pm}$ = $\pm 15$ V, $V_{IC}$ = 0, $T_A$ = $25^{\circ}C$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate		0.2	0.4		V/μs
.,	Employee the section of the continue	f = 10 Hz		24		\ // <del> </del>
V <sub>n</sub>	Equivalent input noise voltage	f = 1 kHz		22	MAX	nV/√ <del>Hz</del>
V <sub>N(PP)</sub>	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 10 Hz		0.55		μV
In	Equivalent input noise current	f = 10 Hz		0.07		pA/√ <del>Hz</del>

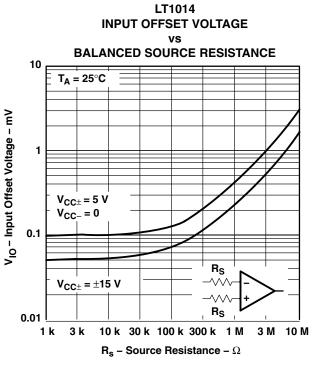


SLOS039D - JULY 1989 - REVISED AUGUST 2009

#### **TYPICAL CHARACTERISTICS**

### **Table of Graphs**

		FIGURE			
V <sub>IO</sub>	Input offset voltage vs Balanced sou	1			
V <sub>IO</sub>	Input offset voltage vs Free-air temp	2			
$\Delta V_{IO}$	Warm-Up Change in input offset vol	3			
I <sub>IO</sub>	Input offset current vs Free-air temp	erature	4		
I <sub>IB</sub>	Input bias current vs Free-air tempe	rature	5		
V <sub>IC</sub>	Common-mode input voltage vs Input	ut bias current	6		
	vs Load resistance				
$A_{VD}$	Differential voltage amplification	vs Frequency	9, 10		
	Channel separation vs Frequency	11			
	Output saturation voltage vs Free-ai	12			
CMRR	Common-mode rejection ratio vs Fre	13			
k <sub>SVR</sub>	Supply-voltage rejection ratio vs Fre	14			
Icc	Supply current vs Free-air temperate	15			
los	Short-circuit output current vs Elaps	16			
V <sub>n</sub>	Equivalent input noise voltage vs Fr	equency	17		
In	Equivalent input noise current vs Fre	17			
V <sub>N(PP)</sub>	Peak-to-peak input noise voltage vs	18			
	Pulse response (small signal) vs Tin	19, 21			
	Pulse response (large signal) vs Tim	20, 22, 23			
	Phase shift vs Frequency		9		



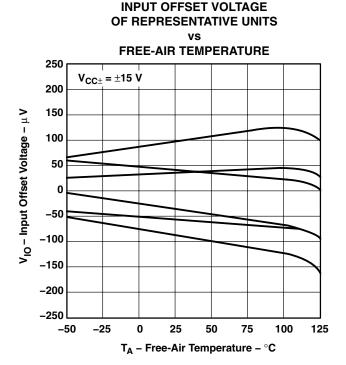
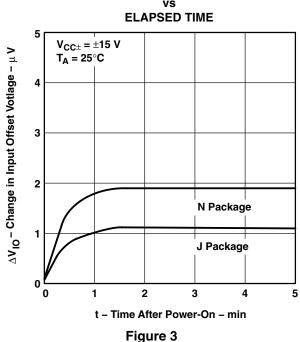


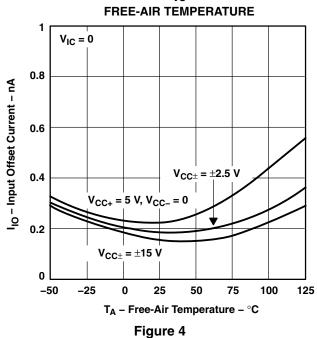
Figure 1



# WARM-UP CHANGE IN INPUT OFFSET VOLTAGE

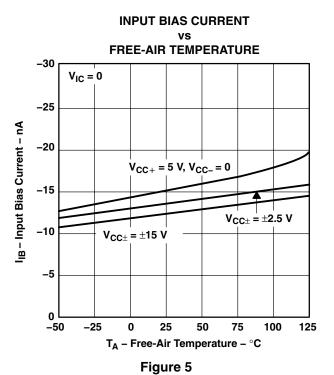


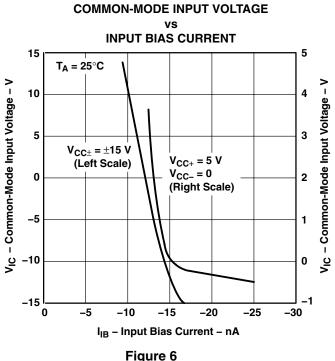
# INPUT OFFSET CURRENT vs

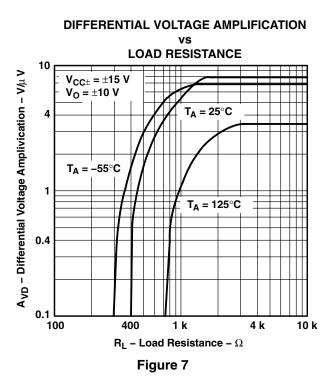


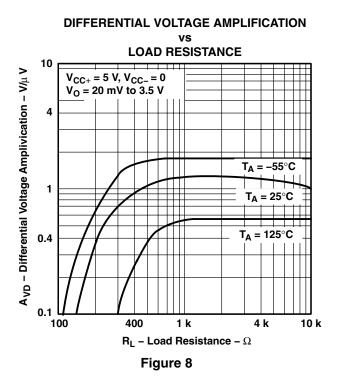
<sup>&</sup>lt;sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.







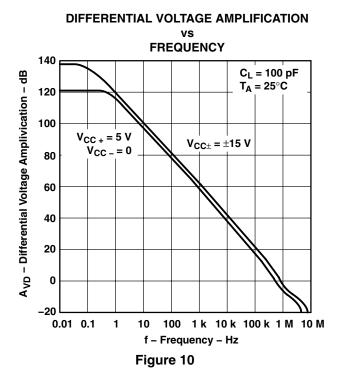


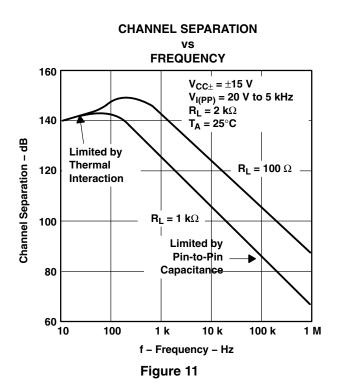


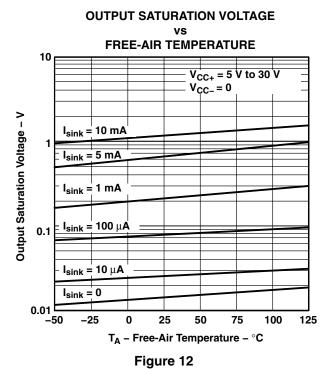
<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



#### **DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT** vs **FREQUENCY** 80° $V_{IC} = 0$ A<sub>VD</sub> - Differential Voltage Amplivication - dB $C_L = 100 pF$ 100° T<sub>A</sub> = 25°C $V_{CC\pm} = \pm 15 \text{ V}$ 120° $V_{CC+} = 5 V$ 140° 091 160° 091 0 − Phase Shiff 10 $V_{CC-} = 0$ $V_{CC+} = 5 V$ 0 $V_{CC-} = 0$ **200**° $V_{CC}\pm = \pm 15 V$ 220° 240° 0.3 0.01 10 f - Frequency - MHz Figure 9

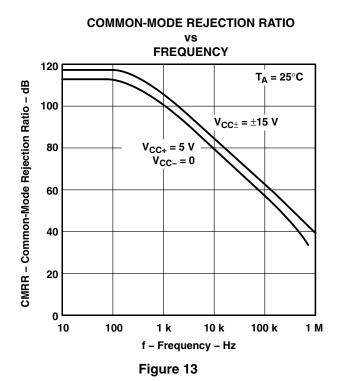


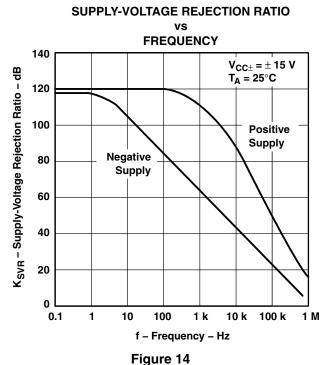


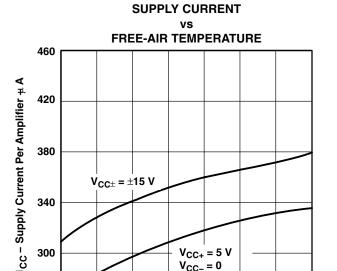


<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.









25

Figure 15

T<sub>A</sub> - Free-Air Temperature - °C

 $V_{CC+} = 5 V$ 

75

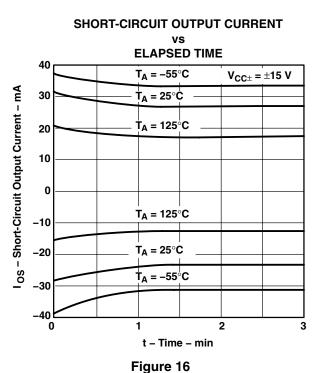
100

 $V_{CC-} = 0$ 

300

260 -50

-25

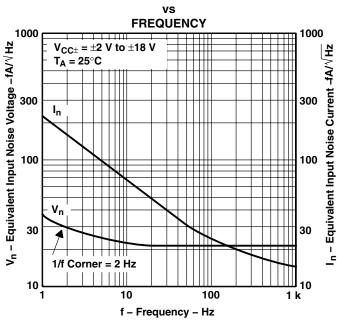


† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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# EQUIVALENT INPUT NOISE VOLTAGE AND EQUIVALENT INPUT NOISE CURRENT



#### Figure 17

#### PEAK-TO-PEAK INPUT NOISE VOLTAGE OVER A 10-SECOND PERIOD

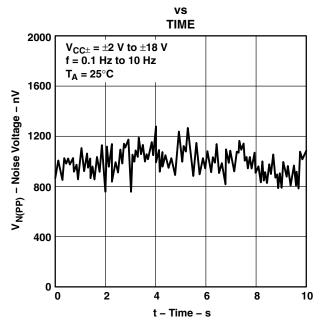


Figure 18

# VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

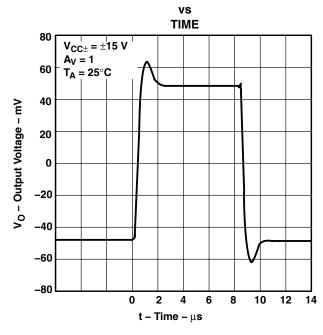


Figure 19

#### VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

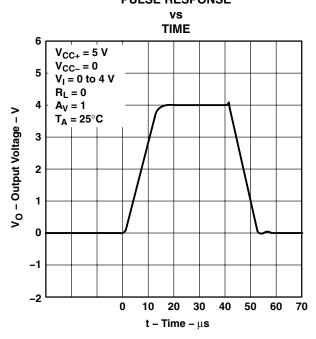
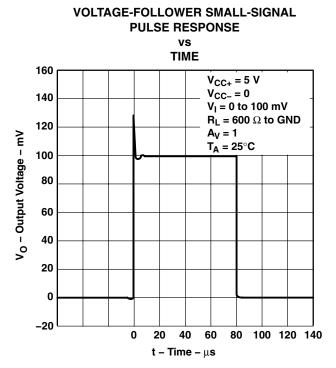


Figure 20



VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

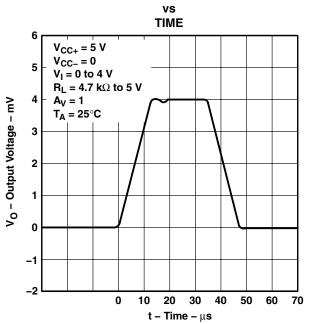


Figure 21 Figure 22

#### VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

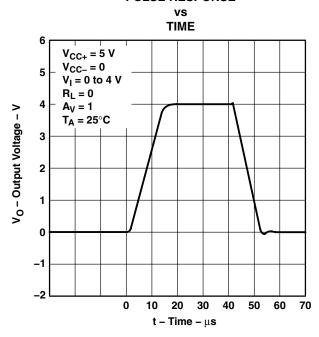


Figure 23



#### single-supply operation

The LT1014 is fully specified for single-supply operation ( $V_{CC-} = 0$ ). The common-mode input voltage range includes ground, and the output swings within a few millivolts of ground.

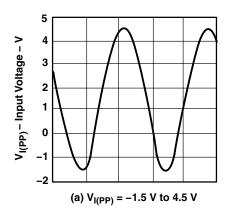
Furthermore, the LT1014 has specific circuitry that addresses the difficulties of single-supply operation, both at the input and at the output. At the input, the driving signal can fall below 0 V, either inadvertently or on a transient basis. If the input is more than a few hundred millivolts below ground, the LT1014 is designed to deal with the following two problems that can occur:

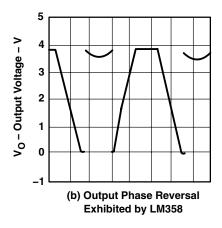
- 1. On many other operational amplifiers, when the input is more than a diode drop below ground, unlimited current flows from the substrate (V<sub>CC</sub> terminal) to the input, which can destroy the unit. On the LT1014, the 400-Ω resistors in series with the input (see schematic) protect the device even when the input is 5 V below ground.
- 2. When the input is more than 400 mV below ground (at  $T_A = 25^{\circ}C$ ), the input stage of similar type operational amplifiers saturates, and phase reversal occurs at the output. This can cause lockup in servo systems. Because of unique phase-reversal protection circuitry (Q21, Q22, Q27, and Q28), the LT1014 outputs do not reverse, even when the inputs are at −1.5 V (see Figure 24).

However, this phase-reversal protection circuitry does not function when the other operational amplifier on the LT1014 is driven hard into negative saturation at the output. Phase-reversal protection does not work on an amplifier:

- When 4's output is in negative saturation (the outputs of 2 and 3 have no effect)
- When 3's output is in negative saturation (the outputs of 1 and 4 have no effect)
- When 2's output is in negative saturation (the outputs of 1 and 4 have no effect)
- When 1's output is in negative saturation (the outputs of 2 and 3 have no effect)

At the output, other single-supply designs either cannot swing to within 600 mV of ground or cannot sink more than a few microproamperes while swinging to ground. The all-npn output stage of the LT1014 maintains its low output resistance and high gain characteristics until the output is saturated. In dual-supply operations, the output stage is free of crossover distortion.





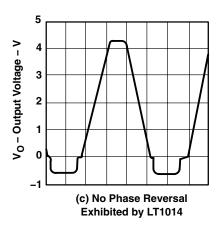
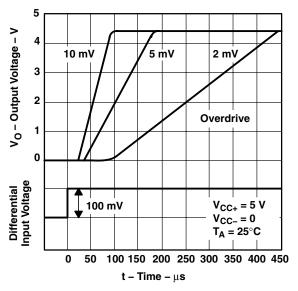


Figure 24. Voltage-Follower Response With Input Exceeding the Negative Common-Mode Input Voltage Range



#### comparator applications

The single-supply operation of the LT1014 can be used as a precision comparator with TTL-compatible output. In systems using both operational amplifiers and comparators, the LT1014 can perform multiple duties (see Figures 25 and 26).



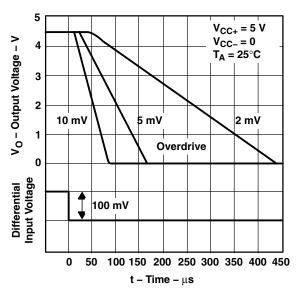


Figure 25. Low-to-High-Level Output Response for Various Input Overdrives

Figure 26. High-to-Low-Level Output Response for Various Input Overdrives

#### low-supply operation

The minimum supply voltage for proper operation of the LT1014 is 3.4 V (three Ni-Cad batteries). Typical supply current at this voltage is 290 µA; therefore, power dissipation is only 1 mW per amplifier.

#### offset voltage and noise testing

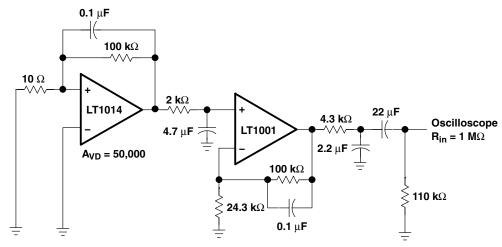
Figure 30 shows the test circuit for measuring input offset voltage and its temperature coefficient. This circuit with supply voltages increased to  $\pm 20$  V is also used as the burn-in configuration.

The peak-to-peak equivalent input noise voltage of the LT1014 is measured using the test circuit shown in Figure 27. The frequency response of the noise tester indicates that the 0.1-Hz corner is defined by only one zero. The test time to measure 0.1-Hz to 10-Hz noise should not exceed 10 seconds, as this time limit acts as an additional zero to eliminate noise contribution from the frequency band below 0.1 Hz.

An input noise-voltage test is recommended when measuring the noise of a large number of units. A 10-Hz input noise-voltage measurement correlates well with a 0.1-Hz peak-to-peak noise reading because both results are determined by the white noise and the location of the 1/f corner frequency.

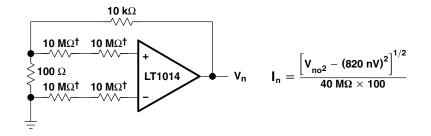
Noise current is measured by the circuit and formula shown in Figure 28. The noise of the source resistors is subtracted.





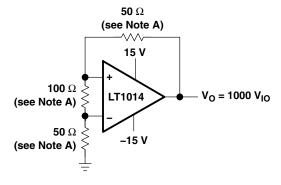
NOTE A: All capacitor values are for nonpolarized capacitors only.

Figure 27. 0.1-Hz to 10-Hz Peak-to-Peak Noise Test Circuit



† Metal-film resistor

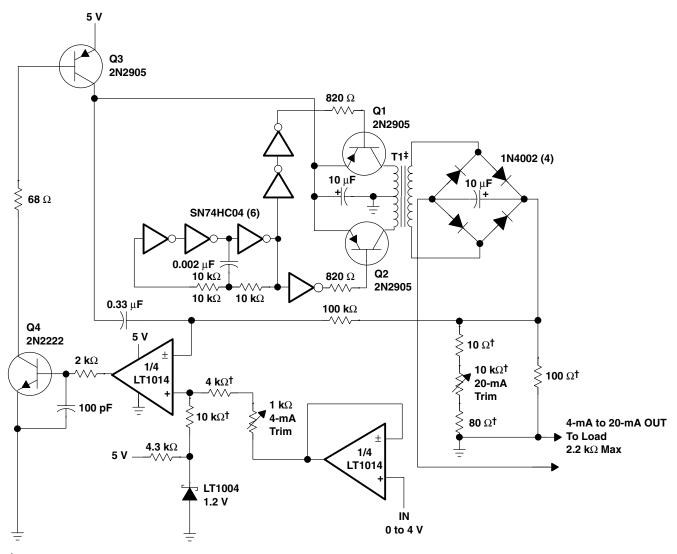
Figure 28. Noise-Current Test Circuit and Formula



NOTE A: Resistors must have low thermoelectric potential.

Figure 29. Test Circuit for  $V_{IO}$  and  $\alpha V_{IO}$ 





 $<sup>^{\</sup>dagger}$  1% film resistor. Match 10-kΩ resistors 0.05%.

Figure 30. 5-V Powered, 4-mA to 20-mA Current-Loop Transmitter With 12-Bit Accuracy

<sup>&</sup>lt;sup>‡</sup> T1 = PICO-31080

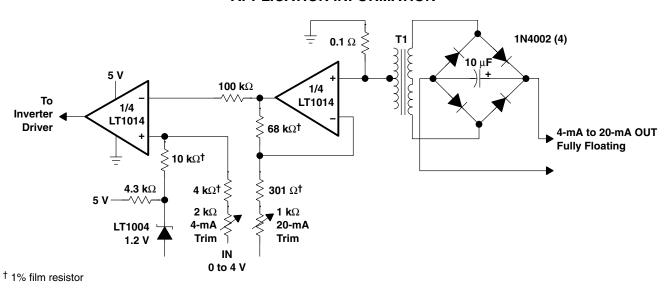
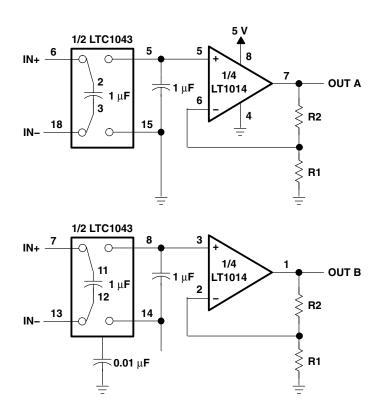


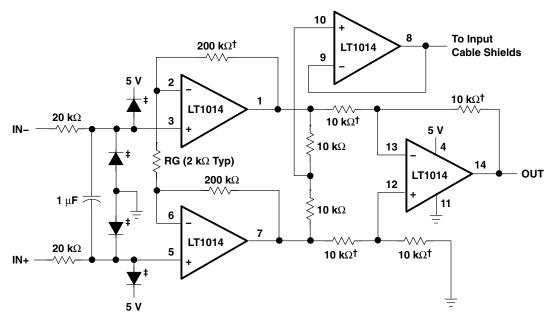
Figure 31. Fully Floating Modification to 4-mA to 20-mA Current-Loop Transmitter With 8-Bit Accuracy



NOTE A:  $V_{IO}$  = 150  $\mu$ V,  $A_{VD}$  = (R1/R2) + 1, CMRR = 120 dB,  $V_{ICR}$  = 0 to 5 V

Figure 32. 5-V Single-Supply Dual Instrumentation Amplifier





 $<sup>^{\</sup>dagger}$  † 1% film resistor. Match 10-k $\Omega$  resistors 0.05%.

NOTE A:  $A_{VD} = (400,000/RG) + 1$ 

Figure 33. 5-V Powered Precision Instrumentation Amplifier

 $<sup>^{\</sup>ddagger}$  For high source impedances, use 2N2222 as diodes (with collector connected to base).





17-Mar-2017

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-89677012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 89677012A LT1014 AMFKB	Samples
5962-8967701CA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8967701CA LT1014AMJB	Samples
5962-89677022A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 89677022A LT1014MFKB	Samples
5962-8967702CA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8967702CA LT1014MJB	Samples
LT1014AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 89677012A LT1014 AMFKB	Samples
LT1014AMJ	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	LT1014AMJ	Samples
LT1014AMJB	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8967701CA LT1014AMJB	Samples
LT1014CN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	LT1014CN	Samples
LT1014CNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	LT1014CN	Samples
LT1014DDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LT1014D	Samples
LT1014DDWE4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LT1014D	Samples
LT1014DDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LT1014D	Samples
LT1014DDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LT1014D	Samples
LT1014DDWRE4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LT1014D	Samples
LT1014DDWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	LT1014D	Samples





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Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
LT1014DIDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	LT1014DI	Samples
LT1014DIDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	LT1014DI	Samples
LT1014DIDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 105	LT1014DI	Samples
LT1014DIN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 105	LT1014DIN	Samples
LT1014DINE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 105	LT1014DIN	Samples
LT1014DMDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	LT1014DM	Samples
LT1014DMDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	LT1014DM	Samples
LT1014DN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	LT1014DN	Samples
LT1014DNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	LT1014DN	Samples
LT1014MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 89677022A LT1014MFKB	Samples
LT1014MJ	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	LT1014MJ	Samples
LT1014MJB	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8967702CA LT1014MJB	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



#### PACKAGE OPTION ADDENDUM

17-Mar-2017

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above. **Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF LT1014D:

■ Enhanced Product: LT1014D-EP

in homogeneous material)

NOTE: Qualified Version Definitions:

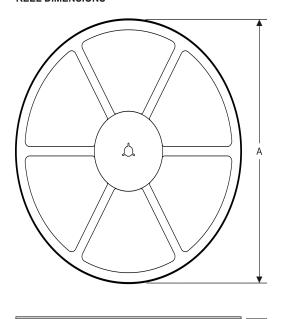
• Enhanced Product - Supports Defense, Aerospace and Medical Applications

### PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**



#### **TAPE DIMENSIONS**



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### TAPE AND REEL INFORMATION

#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LT1014DDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
LT1014DIDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LT1014DDWR	SOIC	DW	16	2000	367.0	367.0	38.0
LT1014DIDWR	SOIC	DW	16	2000	367.0	367.0	38.0

# FK (S-CQCC-N\*\*)

### LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



DW (R-PDSO-G16)

### PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AA.



### 14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

### PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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